

# SiO<sub>2</sub>

SiO<sub>2</sub> is a silicon dioxide dielectric cable designed for specific applications when low-density high-velocity PTFE isn't ideal. These are extreme environmental applications with requirements of:

Extreme temperature from just above absolute zero to 900 °C

A need for strict phase stability

Radiation where cables must withstand up to 100 mega rads



## IDEAL FOR:

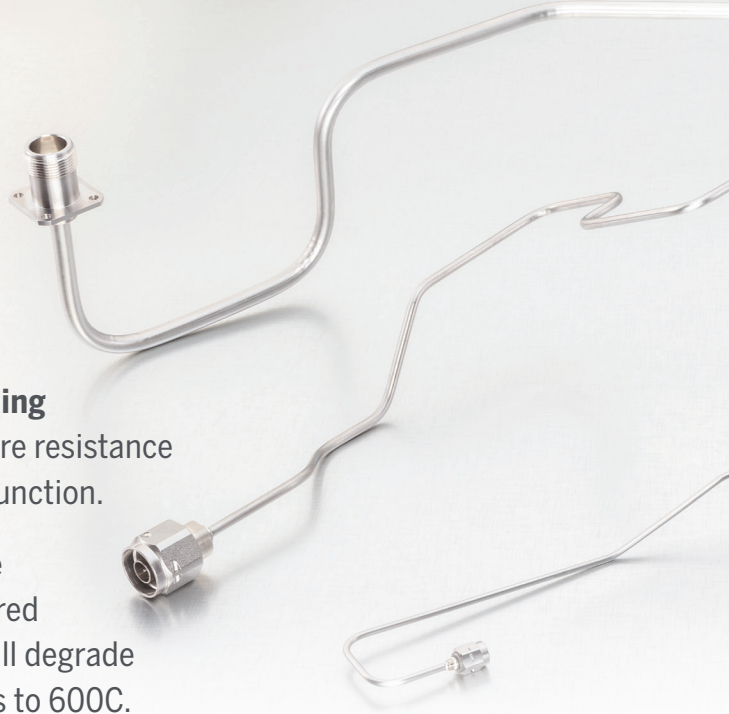
- Hypersonic missiles
  - Deep space
  - Radar systems
  - Rockets
- Particle colliders
- Quantum computing
  - Decoys

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The exceptional performance of SiO<sub>2</sub> in extreme environments stems from its unique construction.

- **304L SS jacket** is a material designed to resist radiation and perform in extreme temperatures.
- Connectors use a unique termination style: **laser welding** instead of soldering. Laser welding increases temperature resistance and provides a hermetic seal at the connector to cable junction.
- SiO<sub>2</sub> connectors utilize **glass to metal seals** to create a hermetic seal at the interface. A hermetic seal is required as the SiO<sub>2</sub> dielectric is a desiccant and performance will degrade with moisture ingress. Cables rated to 900C, connectors to 600C.



Ω Impedance  
50 Ohms

Op Temp  
-454 to +1832°F  
-270 to +900°C

## Specifications

	Units	.090	.125	.141	.270
Maximum Operating Frequency	GHz	40	36	36	18
Velocity of Propagation	%	80.00%	80.00%	80.00%	80.00%
Dielectric Constant	NA	1.56	1.56	1.56	1.56
Capacitance	pF/ft (pF/m)	26.02 (85.37)	25.39 (83.3)	25.59 (83.96)	26.20 (85.96)
Shielding Effectiveness	dB	-110	-110	-110	-110
Diameter	in (mm)	0.090 (2.286)	0.125 (3.175)	0.141 (3.581)	0.270 (6.858)

All stated values are to be taken as nominal

## Phase Change VS Temperature (SiO<sub>2</sub> 0.090")

